



SHENZHEN LONG JING MICRO-ELECTRONICS CO., LTD.

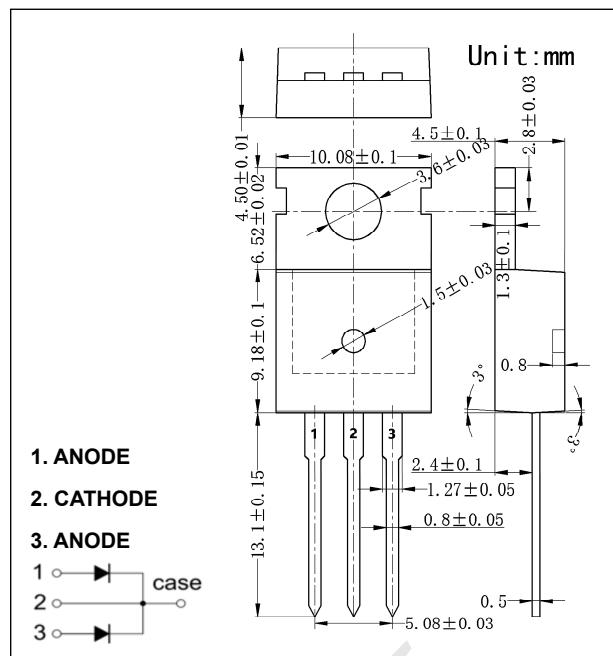
TO-220 Plastic-Encapsulate Diodes

MBR2045VCT

20A Schottky Barrier Rectifier

Features

- Low power loss, high efficiency. High surge capacity
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	45	V
V_{RWM}	Working peak reverse voltage	31.5	
$V_{R(DC)}$	DC blocking voltage	45	
$I_{F(AV)}$	Maximum Average Forward Current	20	A
I_{FSM}	Peak Forward Surge Current: 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	200	A
V_F	Maximum Forward Voltage@10A	0.50	V
I_R	Maximum DC Reverse Current	$T_j = 25^\circ\text{C}$	mA
		$T_j = 125^\circ\text{C}$	mA
$R_{\theta JA}$	Thermal resistance from junction to ambient	50	°C/W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-40~+150	°C

Typical Characteristics

FIG. 1- FORWARD CURRENT DERATING CURVE

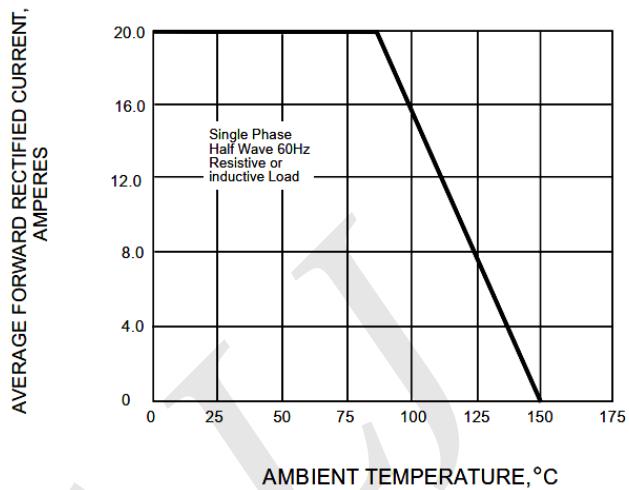


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

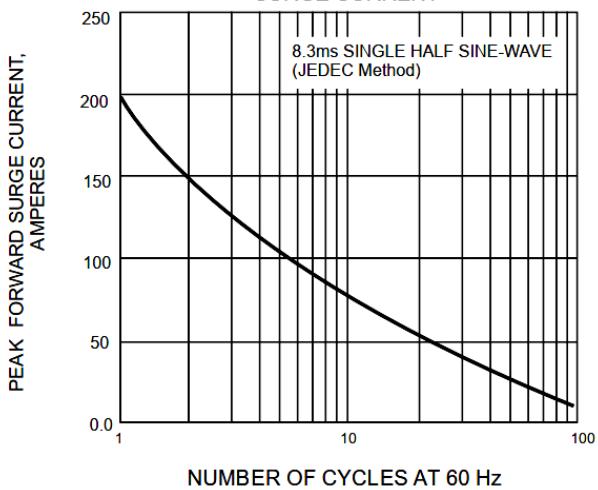


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

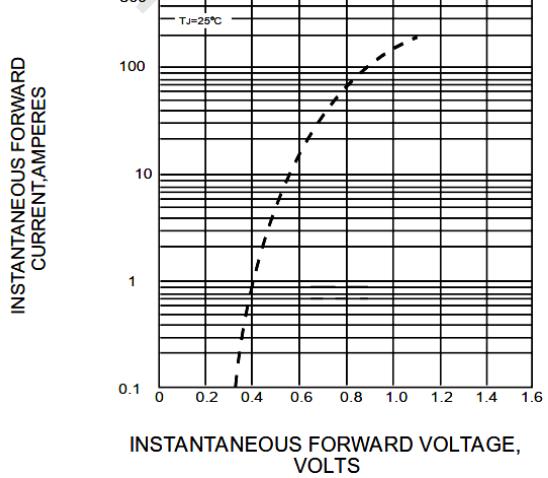


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

